

Specifications	
Part Number	DMN10H120SFG-13
Manufacturer	Displaytech
Description	MOSFET N-CH 100V 3.8A POWERDI
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2766 pcs Stock
Voltage - Test	549pF @ 50V
Voltage - Breakdown	PowerDI3333-8
Vgs(th) (Max) @ Id	110 mOhm @ 3.3A, 10V
Vgs (Max)	6V, 10V
Technology	MOSFET (Metal Oxide)
Series	-
RoHS Status	Tape & Reel (TR)
Rds On (Max) @ Id, Vgs	3.8A (Ta)
Polarization	8-PowerWDFN
Other Names	DMN10H120SFG-13DITR
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Manufacturer Standard Lead Time	16 Weeks
Manufacturer Part Number	DMN10H120SFG-13
Input Capacitance (Ciss) (Max) @ Vds	10.6nC @ 10V
IGBT Type	±20V
Gate Charge (Qg) (Max) @ Vgs	3V @ 250µA
FET Feature	N-Channel
Expanded Description	N-Channel 100V 3.8A (Ta) 1W (Ta) Surface Mount
Drain to Source Voltage (Vdss)	-
Description	MOSFET N-CH 100V 3.8A POWERDI
Current - Continuous Drain (Id) @ 25°C	100V
Capacitance Ratio	1W (Ta)

In:

YIC International Co., Limited.

DMN10H120SE
DIODES
DMN10H120SE DIODES



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DMN10H100SK3
DIODES
DMN10H100SK3 DIODES



DMN10H120SFG-7
Diodes Incorporated
MOSFET N-CH 100V 3.8A
POWERDI



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DMN10H120SFG
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DMN10H120SFG-13
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 MOSFET N-CH 100V 3.8A
 POWERDI

DIODES SEMICONDUCTORS **PERICOM** POWER MANAGEMENT

DMN10H170SFDE
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More

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